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Kind regards,

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INTEGRATED CIRCUITS



Product specification Supersedes data of March 1988 File under Integrated Circuits, IC06 December 1990



FEATURES

- · Schmitt trigger action on all data inputs
- Output capability: standard (open drain)
- I_{CC} category: MSI

GENERAL DESCRIPTION

The 74HC/HCT9114 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT9114 are nine wide Schmitt trigger inverting buffer with open drain outputs and Schmitt trigger inputs.

74HC/HCT9114

The Schmitt trigger action in the data inputs transform slowly changing input signals into sharply defined jitter-free output signals.

The 74HC/HCT9114 have open-drain N-transistor outputs, which are not clamped by a diode connected to V_{CC} . In the OFF-state, i.e. when one input is LOW, the output may be pulled to any voltage between GND and V_{Omax} . This allows the device to be used as a LOW-to-HIGH or HIGH-to-LOW level shifter. For digital operation and OR-tied output applications, these devices must have a pull-up resistor to establish a logic HIGH level.

The "9114" is identical to the "9115" but has inverting outputs.

QUICK REFERENCE DATA

GND = 0 V; T_{amb} = 25 °C; $t_r = t_f = 6 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	ТҮР	TYPICAL		
	PARAMEIER	CONDITIONS	HC	НСТ	UNIT	
t _{PHL} / t _{PLZ}	propagation delay A_n to \overline{Y}_n	C _L = 15 pF; V _{CC} = 5 V	12	13	ns	
CI	input capacitance		3.5	3.5	pF	
C _{PD}	power dissipation capacitance per buffer	notes 1 and 2	5	5	pF	

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz

 $f_o = output frequency in MHz$

 $\Sigma (C_L \times V_{CC}^2 \times f_o) = sum of outputs$

 C_L = output load capacitance in pF

- V_{CC} = supply voltage in V
- 2. For HC the condition is $V_I = GND$ to V_{CC} For HCT the condition is $V_I = GND$ to $V_{CC} - 1.5$ V

ORDERING INFORMATION

See "74HC/HCT/HCU/HCMOS Logic Package Information".

PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1, 2, 3, 4, 5, 6, 7, 8, 9	A ₀ to A ₈	data inputs
10	GND	ground (0 V)
19, 18, 17, 16, 15, 14, 13, 12, 11	\overline{Y}_0 to \overline{Y}_8	data outputs
20	V _{CC}	positive supply voltage



74HC/HCT9114

74HC/HCT9114



FUNCTION TABLE

INPUTS	OUTPUTS
A _n	Ϋ́n
L	Z
Н	L

Notes

- 1. H = HIGH voltage level
 - L = LOW voltage level
 - Z = high impedance OFF-state



74HC/HCT9114

DC CHARACTERISTICS FOR 74HC

For the DC characteristics see *"74HC/HCT/HCU/HCMOS Logic Family Specifications"*. Transfer characteristics are given below.

Output capability: standard I_{CC} category: MSI

TRANSFER CHARACTERISTICS FOR 74HC

Voltages are referred to GND (ground = 0 V)

SYMBOL					T _{amb} (TEST CONDITIONS				
	PARAMETER				74H						
	PARAMETER		+25		-40 t	io +85	-40 te	o +125	UNIT	V _{CC} (V)	WAVEFORMS
		min.	typ.	max.	min.	max.	min.	max.		(•)	
V _{T+}	positive-going threshold	0.70 1.75 2.30	1.13 2.37 3.11	1.50 3.15 4.20	0.70 1.75 2.30	1.50 3.15 4.20	0.70 1.75 2.30	1.50 3.15 4.20	V	2.0 4.5 6.0	Fig.6
V _{T-}	negative-going threshold	0.30 1.35 1.80	0.70 1.80 2.43	1.10 2.40 3.30	0.30 1.35 1.80	1.10 2.40 3.30	0.30 1.35 1.80	1.10 2.40 3.30	V	2.0 4.5 6.0	Fig.6
V _H	hysteresis ($V_{T+} - V_{T-)}$	0.2 0.4 0.5	0.43 0.57 0.68	0.80 1.00 1.10	0.18 0.40 0.50	0.80 1.00 1.10	0.15 0.40 0.50	0.80 1.00 1.10	V	2.0 4.5 6.0	Fig.6

AC CHARACTERISTICS FOR 74HC

 $GND = 0 \ V; \ t_r = t_f = 6 \ ns; \ C_L = 50 \ pF$

		T _{amb} (°C)								TEST CONDITIONS	
SYMBOL	PARAMETER				74HC	;					
STINDOL	FARAMETER		+25		-40 to +85		-40 to +125			V _{CC} (V)	WAVEFORMS
		min.	typ.	max.	min.	max.	min.	max.			
t _{PHL} / t _{PLZ}	propagation delay		36	110		140		165	ns	2.0	Fig.7
	A _n to Yn		13	22		28		33		4.5	
			10	19		24		28		6.0	
t _{THL}	output transition time		19	75		95		110	ns	2.0	Fig.7
			7	15		19		22		4.5	
			6	13		16		19		6.0	

74HC/HCT9114

DC CHARACTERISTICS FOR 74HCT

For the DC characteristics see *"74HC/HCT/HCU/HCMOS Logic Family Specifications"*. Transfer characteristics are given below.

Output capability: standard I_{CC} category: MSI

Note to HCT types

The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given in the family specifications. To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT
A _n	0.3

TRANSFER CHARACTERISTICS FOR 74HCT

Voltages are referred to GND (ground = 0 V)

SYMBOL					T _{amb} (°		TEST CONDITIONS					
	PARAMETER				74HC	т			UNIT			
STNIBOL			+25		-40 t	0 +85	-40 to	o +125		V _{CC} (V)	WAVEFORMS	
		min.	typ.	max.	min.	max.	min.	max.				
V _{T+}	positive-going threshold	0.9 1.2	1.50 1.70	2.0 2.1	0.9 1.2	2.0 2.1	0.9 1.2	2.0 2.1	V	4.5 5.5	Fig.6	
V _{T-}	negative-going threshold	0.7 0.8	1.06 1.27	1.4 1.7	0.7 0.8	1.4 1.7	0.7 0.8	1.4 2.7	V	4.5 5.5	Fig.6	
V _H	hysteresis ($V_{T+} - V_{T-}$)	0.2 0.2	0.44 0.44	0.8 0.8	0.2 0.2	0.8 0.8	0.2 0.2	0.8 0.8	V	4.5 5.5	Fig.6	

AC CHARACTERISTICS FOR 74HCT

 $GND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF$

SYMBOL		T _{amb} (°C)								TEST CONDITIONS	
	PARAMETER				74H0	ст			UNIT		
			+25		-40 t	0 +85	-40 te	o +125		V _{CC} (V)	WAVEFORMS
		min.	typ.	max.	min.	max.	min.	max.			
t _{PHL} / t _{PLZ}	propagation delay A_n to \overline{Y}_n		17	31		39		47	ns	4.5	Fig.7
t _{THL}	output transition time		7	15		19		22	ns	4.5	Fig.7

74HC/HCT9114

TRANSFER CHARACTERISTIC WAVEFORMS



AC WAVEFORMS



PACKAGE OUTLINES

See "74HC/HCT/HCU/HCMOS Logic Package Outlines".